



#### Features:

- **RoHS Compliant** •
- 100 Watts
- DC 2.7 GHz
- **AIN Ceramic**
- **Non-Nichrome Resistive** Element
- Low VSWR
- 100% Tested
- **Small Size**

#### Outline Drawing

## Description

The H100NA20X4 is high performance Aluminum Nitride (AIN) high power flange mount attenuator intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators, and for use in power monitoring. The termination is also RoHS compliant!

### **General Specifications**

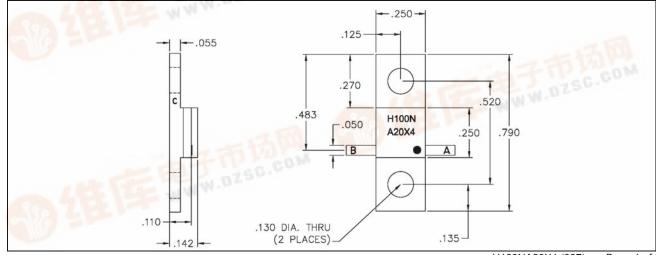
<b>Resistive Element</b>	Thick film
Substrate	AIN Ceramic
Cover	Alumina Ceramic
Mounting Flange	Nickel Plated Copper
<b>Operating Temperature</b>	-55 to +150°C (see de rating chart)
Tolerance is $\pm 0.010^{\circ}$ unless otherwise specified. Designed to meet of exceed	

applicable portions of MIL-E-5400. All dimensions in inches.

#### Electrical Specifications

Attenuation Value:	20 dB, ± 1.0 dB, DC – 4.0GHz
Power:	100 Watts
Frequency Range:	DC – 4.0 GHz
Return Loss	> 24 dB to 2.7 GHz
	> 20 dB to 4.0 GHz

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. Specifications subject to change.



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USA/Canada: Toll Free:

(315) 432-8909 (800) 544-2414

## Model H100NA20X4

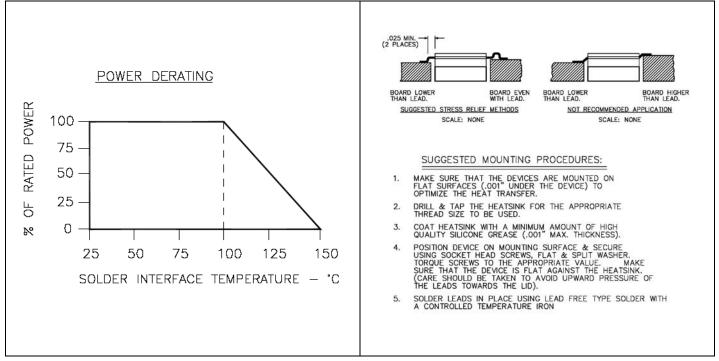
# 



4.00

#### **Typical Performance:** -18.00 -10.00 -19.00 -20.00 Return Loss [dB] Attenuation [dB] -30.00 -20.00 -40.00 -21.00 -50.0 -22.00 3.00 4.0 0.00 0.00 1.00 2.00 1.00 2.00 3.00 F [GHz] F [GHz] Mounting Footprint and Procedure:

**Power De-rating:** 



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